

Single, Dual, and Quad 40V Low Noise Precision Amplifiers

Check for Samples: LMP8671, LMP8672, LMP8674

FEATURES

- **Output Short Circuit Protection**
- **PSRR and CMRR Exceed 110dB**
- Best in Class Linearity (135dB)

APPLICATIONS

- Low Noise Industrial Applications Including Test, Measurement, and Ultrasound
- **Precision Active Filters**
- **PLL Filters**
- 4-20mA Current Loops
- **Motor Control**

KEY SPECIFICATIONS

- Input Offset Voltage 0.4mV
- TC V_{OS} 2µV/°C (max)
- Power Supply Voltage Range ±2.5V to ±20V
- Voltage Noise Density 2.5nV/√Hz
- Slew Rate ±20V/µs
- **Gain Bandwidth Product 55MHz**
- Open Loop Gain 135dB
- **Input Bias Current 10nA**

Connection Diagrams

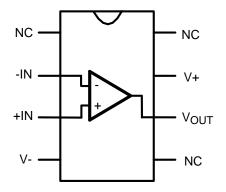


Figure 1. See Package Number — D0008A

DESCRIPTION

The LMP8671/2/4 combines great precision, low noise and a large operating voltage range to provide a high SNR and a wide dynamic range. Its AC performance allows it to be used over a wide frequency without degradation. It is the ideal choice for applications requiring DC precision and low noise such as precision PLL filters, multi feedback and multi pole active filters, GPS receivers and precision control loop systems. The LMP8671/2/4 offers an extremely high open loop gain of 135dB, low voltage noise density (2.5nV/ \sqrt{Hz}), and a superb linearity of 0.000009%. These characteristics drastically reduce gain error which is a challenge in accurate systems requiring higher gains such as data acquisition systems.

To ensure that the most challenging loads are driven without compromise, the LMP8671/2/4 has a high slew rate of ±20V/µs and an output current capability of ±26mA.

The LMP8671/2 family of high-voltage amplifiers are available in SOIC-8, the LMP8674 in SOIC-14.

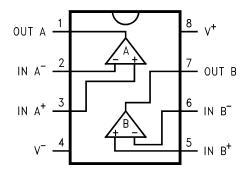


Figure 2. See Package Number — D0008A

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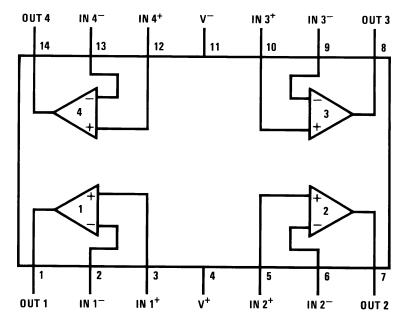


Figure 3. See Package Number — D0014A



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings(1)(2)(3)

Power Supply Voltage (V _S = V ⁺ - V ⁻)		46V	
Storage Temperature		−65°C to 150°C	
Input Voltage	(V-) - 0.7V to (V+) + 0.7V		
Output Short Circuit (4)	Continuous		
Power Dissipation	Internally Limited		
ESD Rating ⁽⁵⁾		2000V	
ESD Rating ⁽⁶⁾	Pins 1, 4, 7 and 8	200V	
	Pins 2, 3, 5 and 6	100V	
Junction Temperature		150°C	
Thermal Resistance	θ _{JA} (SO)	145°C/W	
For soldering specifications, http://www.ti.	.com/lit/SNOA549		

- (1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.
- (2) The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.
- (3) If Military/Aerospace specified devices are required, please contact the TI Sales Office/ Distributors for availability and specifications.
- (4) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX}, θ_{JA}, and the ambient temperature, T_A. The maximum allowable power dissipation is P_{DMAX} = (T_{JMAX} T_A) / θ_{JA} or the number given in *Absolute Maximum Ratings*, whichever is lower.
- (5) Human body model, applicable std. JESD22-A114C.
- (6) Machine model, applicable std. JESD22-A115-A.

Operating Ratings

Temperature Range T _{MIN} ≤ T _A ≤ T _{MAX}	-40°C ≤ T _A ≤ 125°C
Supply Voltage Range LMP8671/2/4	±2.5V ≤ V _S ≤ ±22V

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Electrical Characteristics for the LMP8671/2/4⁽¹⁾

The following specifications apply for $V_S = \pm 20V$, $R_L = 2k\Omega$, $R_{SOURCE} = 10\Omega$, $f_{IN} = 1kHz$, $T_A = 25^{\circ}C$, unless otherwise specified. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	LMP86	71/2/4	Units
Symbol	Parameter	Conditions	Typical ⁽²⁾	Limit ⁽³⁾	(Limits)
V _{OS}	Offset Voltage		±100	±400 ±750	μV (max)
ΔV _{OS} /ΔTemp	Average Input Offset Voltage Drift vs Temperature	-40°C ≤ T _A ≤ 125°C	0.1	2	μV/°C (max)
		V _{CM} = 0V			
	Input Bias Current	LMP8671/4	10	±75 ±95	nA (max)
I _B	input bias current	$V_{CM} = 0V$			
		LMP8672	50	±200 ±250	nA (max)
		V _{CM} = 0V			
I	Input Offset Current	LMP8671/4	11	±50 ±95	nA (max)
los	input Offset Current	$V_{CM} = 0V$			
		LMP8672	25	±100 ±125	nA (max)
ΔI _{OS} /ΔTemp	Input Bias Current Drift vs Temperature	-40°C ≤ T _A ≤ 125°C	0.2		nA/°C
$V_{\text{IN-CM}}$	Common-Mode Input Voltage Range		+17.1 -16.9		V (min) V (min)
Z _{IN}	Differential Input Impedance		30		kΩ
ZIN	Common Mode Input Impedance	-10V <vcm<10v< td=""><td>1000</td><td></td><td>ΜΩ</td></vcm<10v<>	1000		ΜΩ
•	Equivalent Input Noise Voltage	20Hz to 20kHz	0.34	0.65	μV _{RMS} (max)
e _n	Equivalent Input Noise Density	f = 1kHz	2.5	4.7	nV / √Hz (max)
i _n	Current Noise Density	f = 1kHz f = 10Hz	1.6 3.1		pA / √Hz
THD+N	Total Harmonic Distortion + Noise	$A_V = 1$, $V_{OUT} = 3V_{rms}$, $R_L = 600\Omega$	0.00003	0.00009	% (max)
t _S	Settling time	$A_V = -1$, 10V step, $C_L = 100$ pF 0.1% error range	1.2		μs
GBWP	Gain Bandwidth Product		55	45	MHz (min)
SR	Slew Rate		±20	±15	V/µs (min)
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	See ⁽⁴⁾	125	110 100	dB (min)
CMRR	Common-Mode Rejection	-15V≤Vcm≤15V	115	105 100	dB (min)
A _{VOL}	Open Loop Voltage Gain	$-15V \le Vout \le 15V$ R _L = $2k\Omega$	135	125	dB (min)
V _{OUTMAX}	Maximum Output Voltage Swing	$R_L = 2k\Omega$	±19.0	±18.8 ±18.6	V (min)
I _{OUT-CC}	Instantaneous Short Circuit Current		+53 -42		mA

^{(1) &}quot;Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

⁽²⁾ Typical values represent most likely parametric norms at T_A = +25°C, and at the *Recommended Operation Conditions* at the time of product characterization and are not ensured.

⁽³⁾ Datasheet min/max specification limits are ensured by test or statistical analysis.

⁽⁴⁾ PSRR is measured as follows: For V_S , V_{OS} is measured at two supply voltages, $\pm 5V$ and $\pm 20V$, PSRR = $|20\log(\Delta V_{OS}/\Delta V_S)|$.



Electrical Characteristics for the LMP8671/2/4⁽¹⁾ (continued)

The following specifications apply for $V_S = \pm 20V$, $R_L = 2k\Omega$, $R_{SOURCE} = 10\Omega$, $f_{IN} = 1kHz$, $T_A = 25^{\circ}C$, unless otherwise specified. **Boldface** limits apply at the temperature extremes.

Cumbal	Parameter	Conditions	LMP86	LMP8671/2/4			
Symbol	Parameter	Conditions	Typical ⁽²⁾	Limit ⁽³⁾	(Limits)		
R _{OUT}	Output Impedance	f _{IN} = 10kHz Closed-Loop Open-Loop	0.01 13		Ω		
I _{OUT}	Output Current	$R_L = 2k\Omega$	9.5	9.3	mA (min)		
		I _{OUT} = 0mA					
I _S	Total Quiescent Current	LMP8671	5	6 8	mA (max)		
		LMP8672	12.5	16	mA (max)		
		LMP8674	20	22	mA (max)		



Typical Performance Characteristics

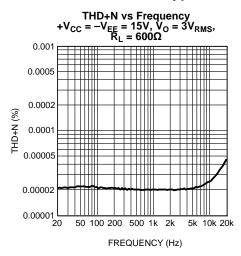


Figure 4.

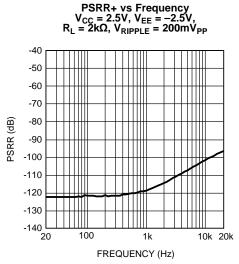
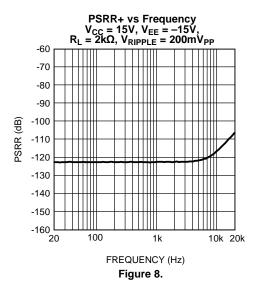


Figure 6.



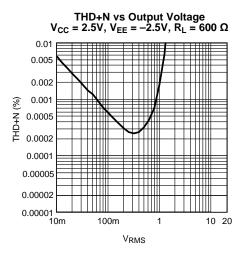


Figure 5.

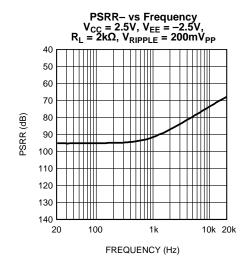
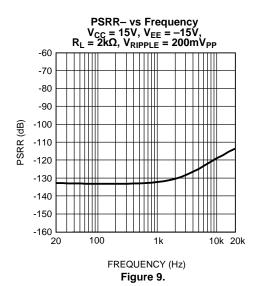


Figure 7.





Typical Performance Characteristics (continued)

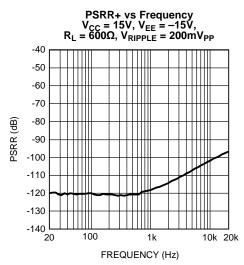


Figure 10.

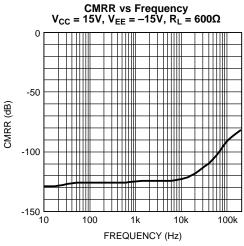


Figure 12.

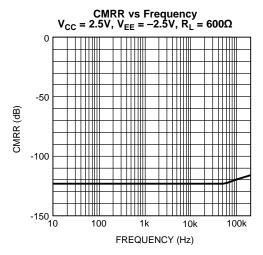


Figure 14.

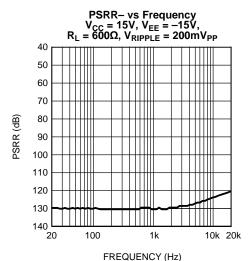


Figure 11.

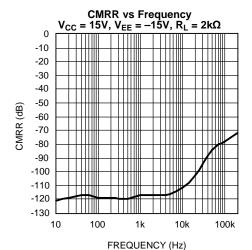


Figure 13.

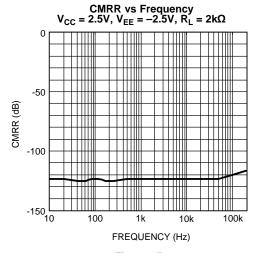


Figure 15.



Typical Performance Characteristics (continued)

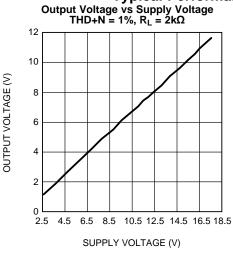


Figure 16.

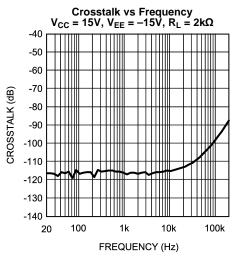


Figure 18.

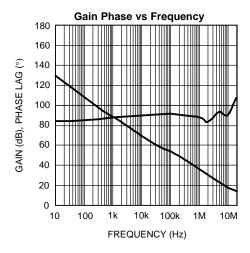


Figure 20.

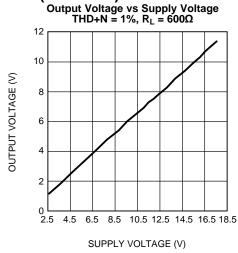


Figure 17.

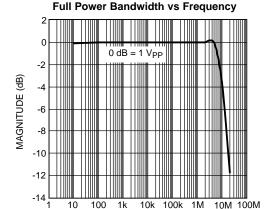


Figure 19.

Voltage Noise Density vs Frequency

FREQUENCY (Hz)

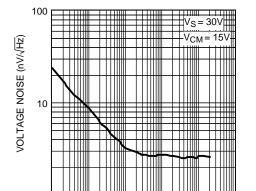


Figure 21.

FREQUENCY (Hz)

100

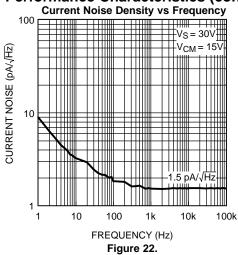
1k

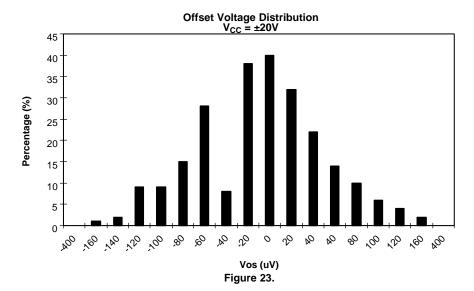
10k

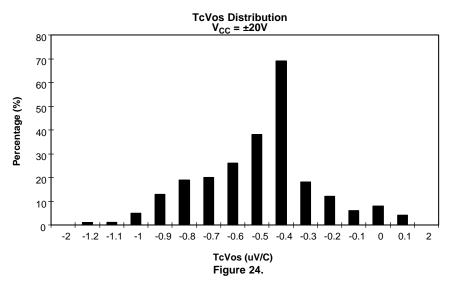
100k



Typical Performance Characteristics (continued) Current Noise Density vs Frequency

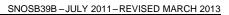








NSTRUMENTS



REVISION HISTORY

Cł	hanges from Revision A (March 2013) to Revision B	Page
•	Changed layout of National Data Sheet to TI format	8

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PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

www.ti.com

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMP8672MA/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	LMP86 72MA	Samples
LMP8672MAX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	LMP86 72MA	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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10-Dec-2020

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	<u> </u>
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMP8672MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

www.ti.com 10-Aug-2018



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
LMP8672MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0	



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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